June 2009

SOT-23 Marking: 3S



2N5551 / MMBT5551 **NPN General Purpose Amplifier**

Features

- This device is designed for general purpose high voltage amplifiers and gas discharge display drivers.
- Suffix "-C" means Center Collector in 2N5551 (1. Emitter 2. Collector 3. Base)
- Suffix "-Y" means h_{FE} 180~240 in 2N5551 (Test condition : I_C = 10mA, V_{CE} = 5.0V)



Absolute Maximum Ratings * $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	160	V	
V _{CBO}	Collector-Base Voltage	180	V	
V _{EBO}	Emitter-Base Voltage	6.0	V	
I _C Collector current - Continuous		600	mA	
T _J , T _{stg}	Junction and Storage Temperature	-55 to +150	°C	

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. NOTES:

1. These ratings are based on a maximum junction temperature of 150 degrees C.

2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Symbol	Parameter	Мах		Units	
		2N5551	*MMBT5551	Units	
PD	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	m₩ m₩/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	200	357	°C/W	

Thermal Characteristics TA=25°C unless otherwise noted

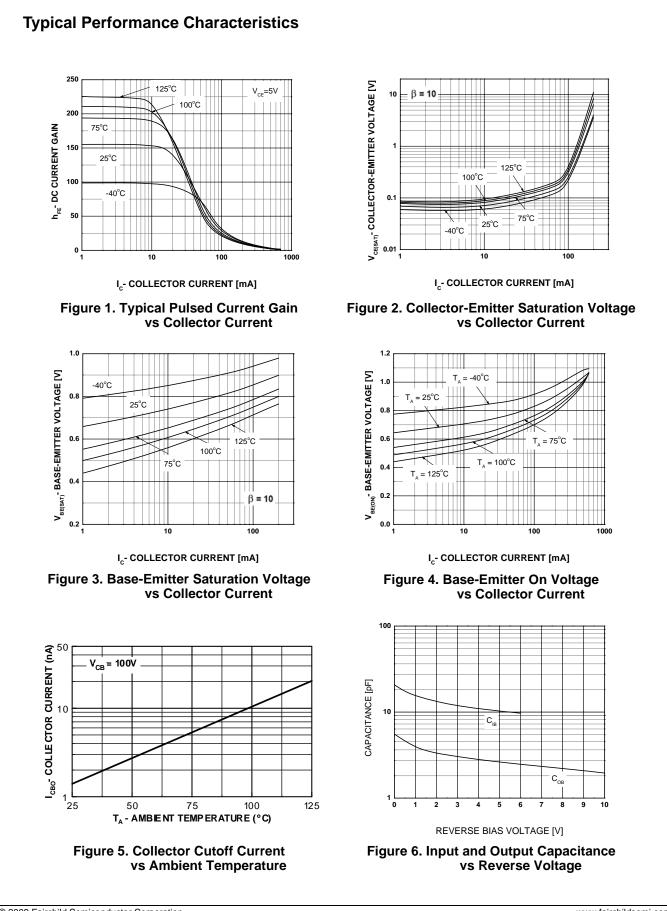
* Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06."

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charac	cteristics		ł		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	160		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	180		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 {\rm uA}, I_{\rm C} = 0$	6.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 120V, I_E = 0$ $V_{CB} = 120V, I_E = 0, T_A = 100^{\circ}C$		50 50	nA μA
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 4.0V, I_{C} = 0$		50	nA
On Charac	teristics			•	
h _{FE}	DC Current Gain	$I_{C} = 1.0mA, V_{CE} = 5.0V$ $I_{C} = 10mA, V_{CE} = 5.0V$ $I_{C} = 50mA, V_{CE} = 5.0V$	80 80 30	250	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{C} = 10$ mA, $I_{B} = 1.0$ mA $I_{C} = 50$ mA, $I_{B} = 5.0$ mA		0.15 0.20	V V
V _{BE(sat)}	Base-Emitter On Voltage	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$		1.0 1.0	V V
Small Sigr	nal Characteristics			•	
f _T	Current Gain Bandwidth Product	$I_{C} = 10$ mA, $V_{CE} = 10$ V, f = 100MHz	100		MHz
C _{obo}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1.0MHz$		6.0	pF
C _{ibo}	Input Capacitance	$V_{BE} = 0.5V, I_{C} = 0, f = 1.0MHz$		20	pF
H _{fe}	Small-Signal Current Gain	$I_{C} = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$	50	250	
NF	Noise Figure	I_{C} = 250 uA, V _{CE} = 5.0 V, R _S =1.0 kΩ, f=10 Hz to 15.7 kHz		8.0	dB

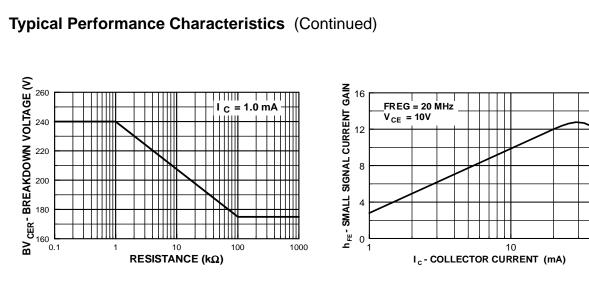
Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Spice Model

NPN (Is=2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 Ne=1.249 Ise=2.511f Ikf=.3458 Xtb=1.5 Br=3.197 Nc=2 Isc=0 Ikr=0 Rc=1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc=.5 Cje=18.79p Mje=.3416 Vje=.75 Tr=1.202n Tf=560p Itf=50m Vtf=5 Xtf=8 Rb=10)



2N5551 / MMBT5551 — NPN General Purpose Amplifier





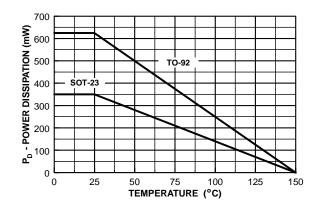
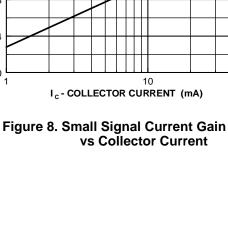


Figure 7. Power Dissipation vs Ambient Temperature



50

FAIRCHILD

SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Auto-SPM™
Build it Now™
CorePLUS™
CorePOWER™
<i>CROSSVOLT</i> ™ CTL™
Current Transfer Logic™
EcoSPARK [®]
EfficentMax™
EZSWITCH™*
E-Z ^{™*}
R
T
Fairchild®
Fairchild Semiconductor [®]
FACT Quiet Series™
FACT® FAST®

F-PFS™ FRFET® Global Power Resource Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MillerDrive™ MotionMax™ Motion-SPM™ **OPTOLOGIC[®] OPTOPLANAR[®]** PDP SPMTM Power-SPM™

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

PowerTrench[®] PowerXS™ Programmable Active Droop™ QFĔT QS™ Quiet Series™ RapidConfigure™ Saving our world, 1mW/W/kW at a time™ SmartMax™ SMART START SPM® STEALTH™ SuperFET™ SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS™ SyncFET™ Sync-Lock™ SYSTEM ®[#] GENERAL

the wer franchise TinyBoost™ TinyBuck™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TriFault Detect™ TRUECURRENT™*

The Power Franchise[®]



UHC[®] Ultra FRFET™ UniFET™ VCX™ VisualMax™ XS™

DISCLAIMER

FastvCore™

FETBench™

FlashWriter®*

FPS™

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS ON NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

Life support devices or systems are devices or systems which, (a) are
intended for surgical implant into the body or (b) support or sustain life,
and (c) whose failure to perform when properly used in accordance
with instructions for use provided in the labeling, can be reasonably
expected to result in a significant injury of the user.

 A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors who are full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms				
Product Status	Definition			
Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.			
First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.			
Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.			
Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.			
	Formative / In Design First Production Full Production			